

# BD439/BD440 BD441/BD442

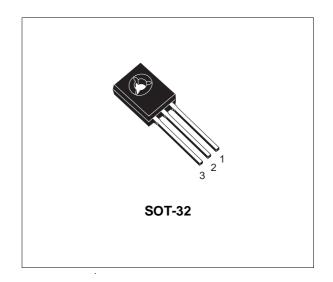
## COMPLEMENTARY SILICON POWER TRANSISTORS

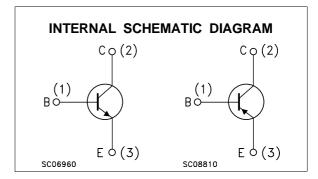
- SGS-THOMSON PREFERRED SALESTYPES
- COMPLEMENTARY PNP NPN DEVICES

#### **DESCRIPTION**

The BD439 and BD441 are silicon epitaxial-base NPN power transistors in Jedec SOT-32 plastic package, intented for use in power linear and switching applications.

The complementary PNP types are BD440, and BD442 respectively.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value			Unit
		NPN	BD439	BD441	
		PNP	BD440	BD442	
V <sub>CBO</sub>	Collector-Base Voltage (I <sub>E</sub> = 0)		60	80	V
V <sub>CES</sub>	Collector-Emitter Voltage (V <sub>BE</sub> = 0)		60	80	V
V <sub>CEO</sub>	Collector-Emitter Voltage (I <sub>B</sub> = 0)		60	80	V
V <sub>EBO</sub>	Emitter-Base Voltage (I <sub>C</sub> = 0)		5		V
Ic	Collector Current		4	4	
I <sub>CM</sub>	Collector Peak Current (t ≤ 10 ms)		7		А
$I_B$	Base Current		1		А
P <sub>tot</sub>	Total Dissipation at T <sub>c</sub> ≤ 25 °C		36		W
T <sub>stg</sub>	Storage Temperature		-65 to 150		°C
Tj	Max. Operating Junction Temperature		15	°C	

For PNP types voltage and current values are negative.

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#### THERMAL DATA

R <sub>thj-case</sub>	Thermal Resistance Junction-case	Max	3.5	°C/W
$R_{thj-amb}$	Thermal Resistance Junction-ambient	Max	100	°C/W

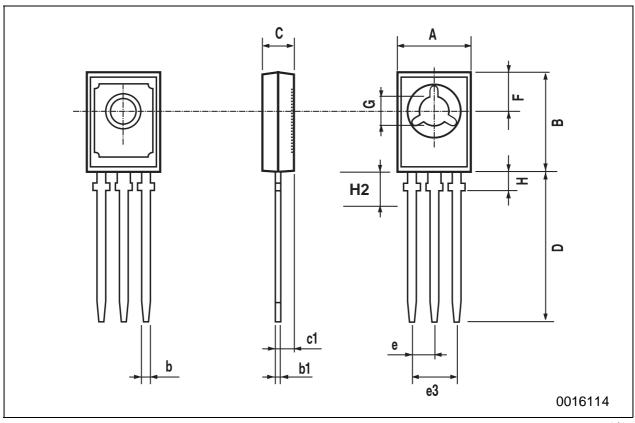
### **ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25$ $^{\circ}C$ unless otherwise specified)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
Ісво	Collector Cut-off Current (I <sub>E</sub> = 0)	for <b>BD439/440</b> for <b>BD441/442</b>	05			100 100	μA μA
Ices	Collector Cut-off Current (V <sub>BE</sub> = 0)	for <b>BD439/440</b> for <b>BD441/442</b>	05			100 100	μA μA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V				1	mA
V <sub>CEO(sus)*</sub>	Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 100 mA	for <b>DB439/440</b> for <b>BD441/442</b>	60 80			V
V <sub>CE(sat)</sub> *	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 2 A	$I_B = 0.2 A$			0.8	V
V <sub>BE</sub> *	Base-Emitter Voltage	I <sub>C</sub> = 10 mA I <sub>C</sub> = 2 A	$V_{CE} = 5 V$ $V_{CE} = 1 V$		0.58	1.5	V
h <sub>FE</sub> *	DC Current Gain	$I_C = 10 \text{ mA}$ $I_C = 500 \text{ mA}$ $I_C = 2 \text{ A}$	V <sub>CE</sub> = 5 V for BD439/440 for BD441/442 V <sub>CE</sub> = 1 V for BD439/440 for BD441/442 V <sub>CE</sub> = 1 V for BD439/440 for BD441/442	20 15 40 40 25 15	130 130 140 140		
h <sub>FE1</sub> /h <sub>FE2</sub> *	Matched Pair	IC = 500 mA	V <sub>CE</sub> = 1 V			1.4	
f⊤	Transition frequency	I <sub>C</sub> = 250 mA	V <sub>CE</sub> = 1 V	3			MHz

<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

# SOT-32 (TO-126) MECHANICAL DATA

DIM.		mm			inch	
Diwi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	7.4		7.8	0.291		0.307
В	10.5		10.8	0.413		0.445
b	0.7		0.9	0.028		0.035
b1	0.49		0.75	0.019		0.030
С	2.4		2.7	0.040		0.106
c1	1.0		1.3	0.039		0.050
D	15.4		16.0	0.606		0.629
е		2.2			0.087	
e3	4.15		4.65	0.163		0.183
F		3.8			0.150	
G	3		3.2	0.118		0.126
Н			2.54			0.100
H2		2.15			0.084	



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